



2814

81754.0048

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Toshihiko HIGUCHI

Serial No: 09/754,818

Filed: January 4, 2001

For: SEMICONDUCTOR DEVICE HAVING A WIRING  
PATTERN AND METHOD FOR MANUFACTURING  
THE SAME (As Amended)Art Unit: 2814  
Examiner: Cao, P.

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Box Non-Fee Amendment, Commissioner for Patents, Washington D.C. 20231, on 09/16/02

Kimberly Yee 09/16/02

Name Date

*Kimberly Yee*  
Signature

Box Non-Fee Amendment  
Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

Transmitted herewith is an Amendment in the above-identified application.

Small entity status has been claimed. See 37 CFR § 1.27.

Three (3) sheets of informal drawings are enclosed.

An Associate Power of Attorney is enclosed.

No additional fee is required.

The fee has been calculated as shown below:

	(Col. 1) CLAIMS REMAINING AFTER AMENDMENT		(Col. 2) HIGHEST NUMBER PREVIOUSLY PAID FOR	(Col. 3) PRESENT EXTRA*	LG/SM \$ ENTITY FEE		ADD'L FEE DUE
TOTAL CLAIMS FEE	20	-	20	**	0	LG=\$18 SM=\$9	\$18.00
INDEPENDENT CLAIMS FEE	7	-	8	***	0	LG=\$84 SM=\$42	\$84.00
FIRST PRESENTATION OF MULTIPLE DEPENDENT CLAIMS						LARGE ENTITY FEE = \$280 SMALL ENTITY FEE = \$140	\$ 0
						TOTAL	\$ 0

\* If the entry in Col. 1 is less than the entry in Col. 2, write "0" in Col. 3.

\*\* If the "Highest Number Previously Paid For" IN THIS SPACE is less than 20, write "20" in this space.

\*\*\* If the "Highest Number Previously Paid For" IN THIS SPACE is less than 3, write "3" in this space. The "Highest Number Previously Paid For" (Total or Independent) is the highest number found from the equivalent box on Col. 1 of a prior amendment or the number of claims originally filed.

A check in the amount of \$ \_\_\_\_\_ to cover the additional claims fee is enclosed. **A copy of this sheet is enclosed.**

A check in the amount of \$ \_\_\_\_\_ to cover the extension of time fee is enclosed. **A copy of this sheet is enclosed.**

The Commissioner is hereby authorized to charge any deficiencies of fees associated with this communication or credit any overpayment to Deposit Account No. 50-1314. **A copy of this sheet is enclosed.**

Any filing fees under 37 C.F.R. § 1.16 for the presentation of extra claims

Any patent application processing fees under 37 C.F.R. § 1.17

Respectfully submitted,  
HOGAN & HARTSON L.L.P.

By:

*Brian D. Martin*

Brian D. Martin

Registration No. 47,771

Attorneys for Applicant

Date: September 16, 2002

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PATENT

Docket No. 81754.0048

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In re application of:

Toshihiko HIGUCHI

Serial No: 09/754,818

Filed: January 4, 2001

For: SEMICONDUCTOR DEVICE HAVING A  
WIRING PATTERN AND METHOD FOR  
MANUFACTURING THE SAME (As  
Amended)

Art Unit: 2814

Examiner: Cao, P.

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Amendment,  
Commissioner for Patents,  
Washington, D.C. 20231, on 9/16/02  
Kimberly Yee 09/16/02  
Name Date  
Kimberly Yee  
Signature

AMENDMENT

Box Non-Fee Amendment  
Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated June 19, 2002, the following  
amendments and remarks are respectfully submitted.

IN THE DRAWINGS:

The applicant has amended Figs. 6-9 by adding the designation "(PRIOR  
ART)" as indicated in red ink correct on the copies of the drawings, attached hereto  
for the Examiner's approval.

IN THE TITLE:

Please replace the title of the invention with the following text:  
"SEMICONDUCTOR DEVICE HAVING A WIRING PATTERN AND  
METHOD FOR MANUFACTURING THE SAME"

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